# NSN 5961-00-813-9029

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Inclosure Material:

Metal

**Overall Length:** 

0.520 inches

# **Overall Diameter:**

1.250 inches

# Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Threaded stud

## Features Provided:

Hermetically sealed case

Thread Size:

0.190 inches

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 collector to emitter voltage, dc and -5.0 emitter to base voltage, dc

## Power Rating Per Characteristic:

150.0 watts total power dissipation

### **Special Features:**

Junction pattern arrangement: npn

### **Test Data Document:**

18876-mis17247 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Thread Series Designator:

Unf

### **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0